



### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>A</sub> = +25°C	
60V	$40m\Omega$ @ $V_{GS} = 10V$	5.0A	
	55mΩ @ V <sub>GS</sub> = 4.5V	4.4A	

### **Features and Benefits**

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Data Sheet (<u>DMN6040SSDQ</u>)

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC Converters
- Power Management Functions
- Backlighting

### **Mechanical Data**

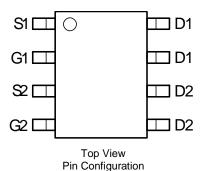
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020

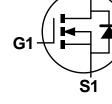
**D1** 

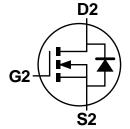
- Terminal Connections: See Diagram
- Terminals: Finish Tin Finish Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 33
- Weight: 0.074 grams (Approximate)



Top View







**Equivalent Circuit** 

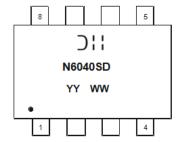
### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMN6040SSD-13	SO-8	2,500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



| = Manufacturer's Marking | N6040SD = Product Type Marking Code | YYWW = Date Code Marking | YY or YY = Year (ex: 16= 2016) | WW = Week (01 - 53)

DMN6040SSD Document number: DS35673 Rev. 5 - 2

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## **Maximum Ratings** (@T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	$V_{DSS}$	60	V		
Gate-Source Voltage	$V_{GSS}$	±20	V		
Continuous Dusin Coursest (Note CVV 40V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	5.0 4.1	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	6.6 5.3	А
Maximum Body Diode Forward Current (Note 6)	Is	2.5	Α		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	30	Α		
Pulsed Body Diode Forward Current (10µs Pulse, Du	I <sub>SM</sub>	30	Α		
Avalanche Current (Note 7) L = 0.1mH	I <sub>AS</sub>	14.2	Α		
Avalanche Energy (Note 7) L = 0.1mH	E <sub>AS</sub>	10	mJ		

### Thermal Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)	$T_A = +25$ °C	Ь	1.3	W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	$P_{D}$	0.8	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	102	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	61	
Total Power Dissipation (Note 6)	$T_A = +25$ °C	Ъ	1.7	W
Total Fower Dissipation (Note o)	$T_A = +70^{\circ}C$	P <sub>D</sub>	1.1	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	75	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R <sub>0JA</sub>	50	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	14.5	
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

# **Electrical Characteristics** (@T<sub>A</sub> = 25°C unless otherwise specified)

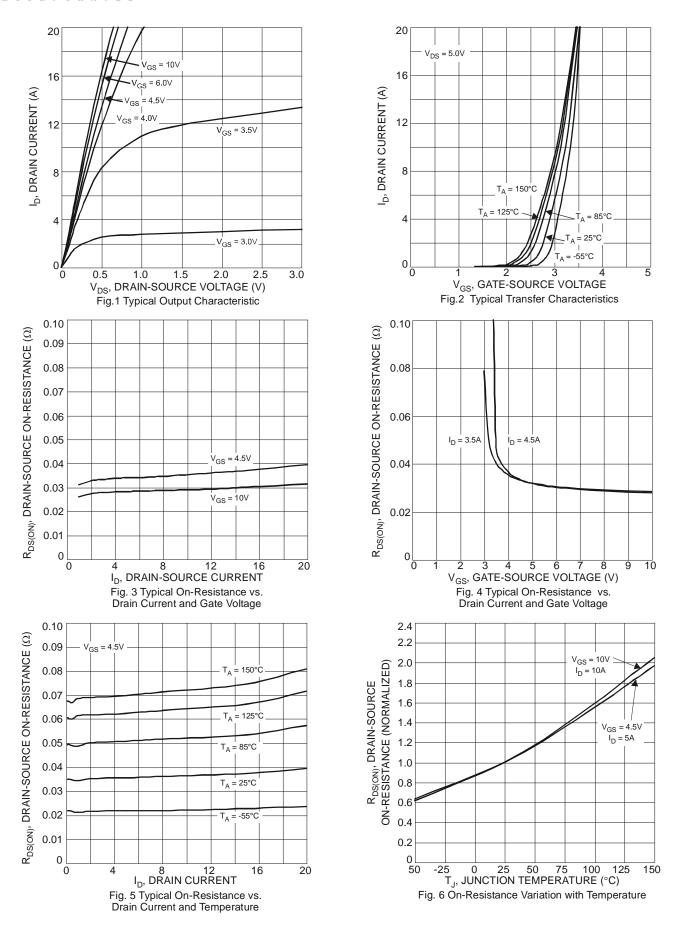
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	100	nA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1		3	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance			30	40	mΩ	$V_{GS} = 10V, I_D = 4.5A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		35	55	11122	$V_{GS} = 4.5V, I_D = 3.5A$	
Forward Transfer Admittance	Y <sub>FS</sub>		4.5	_	S	$V_{DS} = 10V, I_D = 4.3A$	
Diode Forward Voltage	$V_{SD}$		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>ISS</sub>		1,287	_		V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss	_	57	_	pF		
Reverse Transfer Capacitance	C <sub>RSS</sub>	_	44	_			
Gate Resistance	$R_{G}$	_	1.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_G$		22.4	_			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_{G}$	_	10.4	_	nC	$V_{DS} = 30V, I_D = 4.3A$	
Gate-Source Charge	$Q_{GS}$	_	4.9	_	IIC IIC		
Gate-Drain Charge	$Q_{GD}$	_	3.0	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.6			$V_{GS} = 10V, V_{DD} = 30V, R_G = 6\Omega,$ $I_D = 4.3A$	
Turn-On Rise Time	t <sub>R</sub>	_	8.1	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	20.1	_	ns		
Turn-Off Fall Time	t <sub>F</sub>		4.0				
Body Diode Reverse Recovery Time	t <sub>RR</sub>		18		ns	I <sub>S</sub> = 4.3A, di/dt = 100A/μs	
Body Diode Reverse Recovery Charge	$Q_{RR}$		11.9	_	nC	$I_S = 4.3A$ , di/dt = 100A/ $\mu$ s	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

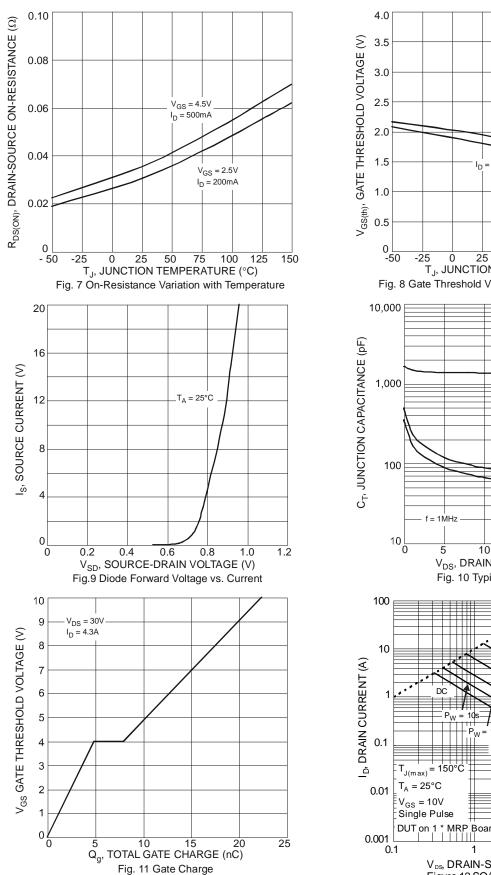
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 7.  $I_{AS}$  and  $E_{AS}$  rating are based on low frequency and duty cycles to keep  $T_{J}$  = +25°C.
- 8. Short duration pulse test used to minimize self-heating effect.
- Guaranteed by design. Not subject to product testing.

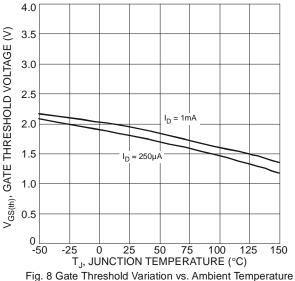
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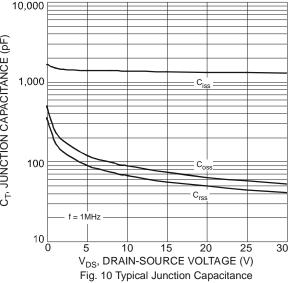


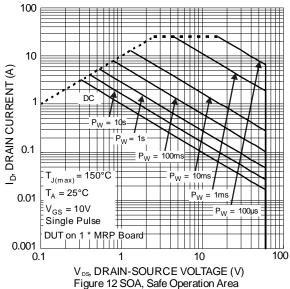




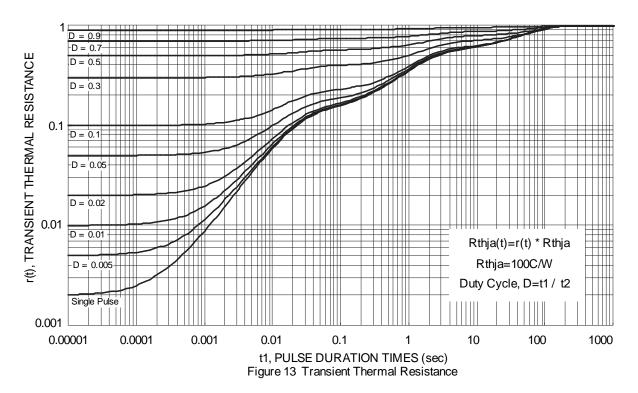










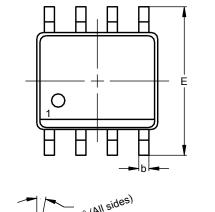


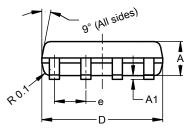


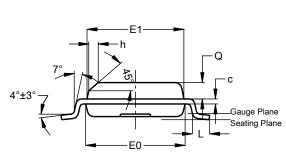
# **Package Outline Dimensions**

 $\label{please} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

**SO-8** 



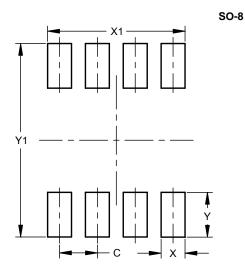




SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h	-		0.35		
Г	0.62	0.82	0.72		
Ø	0.60	0.70	0.65		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
V1	6.50



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